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Hopping conduction mechanism and impedance spectroscopy analyses of La_{0.70}Sr_{0.25}Na_{0.05}Mn_{0.70}Ti_{0.30}O₃ ceramic

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Abstract

The perovskite sample La_{0.7}Sr_{0.25}Na_{0.05}Mn_{0.7}Ti_{0.3}O₃ (LSNM_{0.70}T_{0.30}) was produced via a solid-state route process. Impedance spectra of LSNM_{0.70}T_{0.30} in the frequency interval [40Hz - 1MHz] were studied at several temperatures [80K to 440 K]. The ac conductivity (σ_{ac}) established that according to the Jonscher law. σ_{ac} is described by Non-overlapping Small Polaron Tunneling model at low temperatures and Correlated Barrier Hopping model at high temperatures. From dc conductance analysis, conduction seems to be thermally activated, suggesting the existence of semiconductor process. Detailed investigation of impedance data revealed the non-Debye nature of the relaxation processes in the sample. In addition, Dielectric constant curves were applied to examine the relaxation dynamics of charge carriers. In fact, the Debye-like relaxation was performed on the basis of the polarization of spatial charges following Maxwell-Wagner model and Koop's phenomenological theory.

Keywords: Perovskite, Relaxation process, Oxygen vacancies, Impedance spectroscopy.

1. Introduction

Demand for powerful nanotechnology application is generating challenge among scientists and engineers to provide a stable and flexible system. In fact, more compounds have been suggested in this context and some perfection was achieved in various study fields by the perovskite system, for example, magneto-tunable photocurrent activity, Spin Hall-Magnetoresistive devices and electrocatalytic activity [1-3].

Perovskite manganese oxide with an AMnO_3 general formula may be the next-generation sample for clean energy and large-scale energy storage due to its dual feature of magnetic/electric properties and its diverse applications [4,5]. Its multiferroic nature demonstrates the strong influence of its morphological characteristics on the magneto-transport behavior explained in the framework of Zener's theory [6, 7].

However, manganite exhibits an important effect known as colossal magneto-resistance (CMR) closely related to its magnetic transition between a paramagnetic/insulating phase and ferromagnetic/metal phase [8-10]. The insulator-metal transition is due to the partial doped of the Rare Earth (RE) site by Alkaline Earth (AE) ions, causing the manganese ions to be trained in a combination of Mn^{3+} / Mn^{4+} ions. It was thought that spin system and magneto-transport characteristics are related by the double exchange interaction caused by the motion of the e_g electrons for Mn^{3+} / Mn^{4+} ions [11-14]. The mixed valence state of manganese ($\text{Mn}^{3+}/\text{Mn}^{4+}$) of these compounds displays the prominent role to alternate.

S. El Kossi et al. [15] explore the effect of incorporating a compound to affect the electrical characteristics, i.e. the connection between the electrical and the chemical characteristics. This variation in the conductivity value can be explained by morphological and the random distribution of cations in the lattice by raising concentration of the oxygen vacancy (V_o), resulting from the effects of the charge compensation produced via the incorporation of (Sr, Na) ions into the La-site and Ti ion into site Mn for LaMnO_3 .

In the present investigation, we report on the conduction process, the electrical characteristics and the behavior of the relaxation process of $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic synthesized via the solid state process. In addition, we discuss the conduction mechanism and dielectric relaxation determined by impedance spectroscopy (IS), showing the low acquired dielectric loss.

2. Experimental procedure

In this work, the sample $\text{LSNM}_{0.70}\text{T}_{0.30}$ was produced by the solid state process reported in the previous research [16]. The precursors of metals La_2O_3 , SrCO_3 , Na_2O_3 , TiO_2 and MnO_2 (all Aldrich makes 99.99%). The synthesis procedure is (stepwise) given in Fig.1.

The X-ray pattern after the Rietveld refinement is examined in the previous paper [16]. Note that LSNM_{0.70}T_{0.30} crystallizes in rhombohedral (R-3c) pattern with no visible secondary phase, with lattice parameters $a=b=5.536(3)$ Å, $c=13.438(3)$ Å and cell volume $V=356.75(2)$ Å³.

The dielectric data were derived from ceramic disks after depositing gold electrodes on the circular faces by cathodic sputtering via an IS data employ an N4L-NumetriQ type PSM1735.

3. Results and discussion

3.1 Conductivity analysis

The conductivity spectra $\sigma(\omega)$ of the LSNM_{0.70}T_{0.30} compound at various temperatures over the wide frequency interval are illustrated **Fig. 2(a)**. In the lower frequency range, the $\sigma(\omega)$ increased with the rise of temperature. The $\sigma(\omega)$ against frequency data exhibited more model properties such as dispersion, low frequency plateau and high frequency dispersion. The change in the $\sigma(\omega)$ slopes was found in the lower and higher frequency areas. The apparent low frequency plateau is frequency independent that correlates to the dc conductivity (σ_{dc}) and reveals long-distance mobility of the charge carriers. This low frequency plateau rose with increasing temperature, causing long-distance motion of the charge carriers. The frequency dispersions, produced by short and long -distance mobility of charge carriers, is due to the input of electrical conductivities in LSNM_{0.70}T_{0.30} compound, respectively.

In fact, the σ_{dc} rose with raising the temperature, indicating a semiconductor nature in the LSNM_{0.70}T_{0.30} compound.

Generally, the total electrical conductivity $\sigma(\omega)$ of the LSNM_{0.70}T_{0.30} sample respects Jonscher's law described as [17]:

$$\sigma(\omega) = \sigma_{dc} + \sigma_{ac} = \sigma_{dc} + A\omega^s \quad (1)$$

Where $A\omega^s$ represents the transport behavior of the charge carrier within the polycrystalline compounds and 's' gives details on the level of collaboration between mobile carriers and lattice. Both parameters 'A' and 's' depend on the temperature and the nature of the compound.

3.1.1 ac conductivity study

The experimental conductivity measurements adjusted by the equation (Eq. (1)) to determine the exponents (s) with temperature. The inset of **Fig. 2(a)** depicts an example of adjustment of the data for the temperature 100 K.

Figure 2 displays the evolution of the parameter "s" which rose with temperature increase (in the range [80K-200 K]) and then decreased in the range [200K-440 K], indicating that both conduction processes are present. So, depending on this evolution, Non-Overlapping Small

Polaron Tunneling (NSPT) and Correlated Barrier Hopping (CBH) are the suitable models, respectively.

Similar results were found for La_{0.67-x}Eu_xBa_{0.33}Mn_{0.85}Fe_{0.15}O₃ manganites [18], La_{0.9}Sr_{0.1}MnO₃ ceramic [19].

For the NSPT model, the parameter “s” rose with temperature increase, in a covalent solid. The supplementing of the charge carriers to a site caused local deformation of the system. The mixture of electrons and its local deformation forms a Polaron and the energy of the states diminished via an order of W_p (the Polaron Energy).

The term “Small Polaron” suggests that these particles are so focused which made their deformation clouds non-overlapping [20].

In the NSPT model, the process relates to the potential barrier (W_H) between both sites. σ_{ac} is obtained from the expression [21]:

$$\sigma_{ac} = \frac{(\pi e)^2 k_B T \omega (N(E_F))^2 R_w^4}{12\alpha} \quad (2)$$

Where N(E_F) , α⁻¹ and R_w are , respectively, the density of states close the Fermi level, the spatial extension of the polaron and the tunneling distance.

The exponent “s” may be expressed according to [22]:

$$s = 1 - \frac{4k_B T}{W_H + k_B T \ln(\omega \tau_0)} \quad (3)$$

Where W_H is the potential barrier, τ₀ (=1/ω=1/2πf) is conductivity relaxation time and k_B is Boltzmann’s constant.

At high values of the ratio W_H/k_BT , Eq (3) becomes:

$$s = 1 + \frac{4k_B T}{W_H} \quad (4)$$

In the CBH model, the parameter “s” decreased with temperature increase. The conduction was carried by the jump of electrons above a Coulomb barrier which divides it [23].

σ_{ac} is obtained from the expression:

$$\sigma_{ac} = \frac{n\pi N N_p \epsilon' \epsilon_0 \omega R_\omega^6}{24} \quad (5)$$

Where n is polaron number implicated in jumping behavior, N indicates density of localized states in which the carriers are present, N_p characterizes density of localized states in which carriers jump, ε₀ indicates the dielectric constant of the free space.

In this type of conduction, the potential barrier (W_M) in the CBH model is described as follows [24]:

$$s = 1 - \frac{6k_B T}{W_M + k_B T \ln(\omega \tau_0)} \quad (6)$$

To estimate large $W_M/K_B T$ values, the parameter “s” was minimized to:

$$s = 1 - \frac{6k_B T}{W_M} \quad (7)$$

The W_H and W_M were determined from the linear adjustment of the empirical data 1-s against temperature. Their values were $W_H = 0.087$ eV and $W_M = 0.12$ eV (**Fig. 2(b)**).

In addition, as observed, temperature increase led term increase in the binding energy of the charge carriers that can hardly hop from one site to the next with more energy needed [25]

3.1.2 dc conductivity study

σ_{dc} of the $LSNM_{0.70}T_{0.30}$ sample is a concept of thermal process and according to Arrhenius' law described as follows:

$$\sigma_{dc} = \sigma_0 \exp\left(-\frac{E_a}{k_B T}\right) \quad (8)$$

Where σ_0 is a pre-exponential parameter and K_B is Boltzmann's constant.

The values of E_a are determined via the slope of $\log(\sigma_{dc} \cdot T)$ against $1000/T$ in the inset of **Fig. 2(c)**. So, E_a values around 0.16 eV found for conduction are very similar to these of the E_a of V_o in the perovskite type [26]. The transport mechanism can take place by a single or bipolaron hopping behavior over the barrier between the grain and grain boundary sites in the CBH model. The small polaron is produced from Jahn-Teller electron-phonon combination of the Mn^{3+} ions. On the variation of the temperature, the bipolaron can be created as the number of free carriers rises. Indeed, the rise in temperature causes an elevation in the density of free carriers, which leads to the reduction of the encountered barriers and the enhancement of conductivity [27-29]. The scaling process of conductivity spectra of $LSNM_{0.70}T_{0.30}$ ceramic is illustrated **Fig. 2(d)**. We can note that all the curve superimposed to produce a unique master line. The overlapping of measurements at several temperatures indicates that the process of electrical ion conduction in the $LSNM_{0.70}T_{0.30}$ sample is not linked to temperature, but to a short distance attributed to the polarization of the electrode, in the low frequency interval and at high temperature.

3.2.2 Complex impedance analysis

The variation of the real part (Z') of impedance against the frequency for $LSNM_{0.70}T_{0.30}$ ceramic is displayed in **Fig. 3(a)** for a T range [80K-440K]. The magnitude of Z' is nearly independent

of frequency, at a fixed temperature and at low frequencies, which indicates a Negative Temperature Coefficient of the Resistance [30]. In addition, the significant reduction in the magnitude of Z' with temperature rise shows the rise in the conductivity. This may be explained to improve mobility and reduced trapped charge density [31]. The evolution of Z' against the temperature gradually decreased and then disappeared by further increasing the frequencies. This behavior can validate the existence of polarization of the space charge in the $\text{LSNM}_{0.70}\text{T}_{0.30}$ sample [32]. Also, we may see a shift in the plateau of Z' , indicating existence of a frequency relaxation behavior in the $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic [33,34].

Further investigations on the intrinsic property of the compounds were performed. The average Normalized Change (ANC) analysis is described via the following equation [35]:

$$ANC = \frac{\Delta Z'/\Delta f}{Z_0} \quad (9)$$

Where Z_0 (Z' value at frequency near to zero) can be roughly evaluated via the extrapolation of the low frequency response, $\Delta Z' = Z'_{\text{high}} - Z'_{\text{low}}$ with $Z'_{\text{low}}/Z'_{\text{high}}$ are the Z' value at low/ high frequency $f_{\text{low}}/f_{\text{high}}$ and $\Delta f = f_{\text{high}} - f_{\text{low}}$. The temperature dependence of the ANC is illustrated in **Fig. 3(b)**. As expected, on rising temperature, we can see clearly that the shape of the flow curves reveals the presence of various conduction mechanisms and density of trapped charges markedly decreased. The amount of releasing trapped charge from such intrinsic defects in materials was examined by the slope of the differential of ANC. Noticeably, a modification of the slope of the differential of the ANC (inset of **Fig. 3(b)**), was detected around 250 K for $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic.

The spectrum of impedance (Z'') against the frequency at [80K-440K] for $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic is displayed in **Fig. 3(c)**. All data presented a peak at a specific frequency f_{max} . The maximal value is indicated Z''_{max} .

The relaxation frequency f_{max} changed to the higher frequency with temperature increase, confirming presence of a relaxation behavior in temperature and frequency [26]. The relaxation time is calculated according to the equation $\tau = 1/(2\pi f_{\text{max}})$.

The reciprocal relationship between τ and temperature is illustrated in **Fig. 3(d)**. The temperature connected of τ^z obeys the Arrhenius' function as follows:

$$\tau^z = \tau_0^z \exp\left(-\frac{E_a^z}{k_B T}\right) \quad (10)$$

Where k_B is Boltzmann constant and τ_0^z is the pre-exponential factor.

The E_a^Z values obtained via fitting of the Arrhenius graph (shown in **Fig. 3(d)**) are represented as $\ln(\tau^Z)$ as a function of $1000/T$. We remark that E_a^Z is about 0.13 eV. This process is related to V_o [36].

The Z''/Z''_{\max} curve against of frequency for the $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic is displayed in **Fig. 3(e)**. It is obvious that temperature evolution caused the collapse of all the lines into one line with minor differences. Thus, the repartition of the relaxation behavior can be regarded as unrelated with temperature. In addition, the Full Width at Half maximum was about 1.14. The findings indicated that the distribution of relaxation at various times is invariant and mechanism caused is a non-Debye type [37,38].

Furthermore, **Fig. 3(f)** illustrates , at $T = 160$ K, curve Z''/Z''_{\max} and $d(Z''/Z''_{\max})/df$ for the $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic. As seen, the position of the maximum of the data of Z''/Z''_{\max} did not coincide with the position of the data of $d(Z''/Z''_{\max})/df$. This shift or non-coincidence indicates the non-Debye mechanism [37,38].

3.2.3 Electric Modulus analysis

Complex modulus M^* is calculated as follows [39]:

$$M^* = M' + jM'' = j\omega C_0 Z^* = \omega C_0 (Z' + jZ'') \quad (11)$$

Where (M', Z') and (M'', Z'') are the real and imaginary parts of M^* and Z^* , respectively; C_0 is the vacuum capacitance of the measured cell and the electrodes with an air gap of the $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic thickness.

The frequency related to $M'(\omega)$ at selected temperatures [80-440K] of $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic is presented in **Fig. 4(a)**. At low frequency, $M'(\omega)$ data tended to zero.

The appearance of the conduction behavior of short-distance mobility can account for the monotonic dispersion when raising the frequency and show the low, contribution of the electrode phenomenon [37].

Figure. 4(b) illustrates the plot of $M''(\omega)$ of $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic for selected temperatures. We observed well-resolved peaks in typical frequency (f_{\max}). In addition, the asymmetric character of $M''(\omega)$ is noticed in the region of dispersion and the peak moved to the higher frequency side on raising the temperature. This suggests that the rise in relaxation with temperature increase is caused by the thermal activation of charge carriers.

Indeed, this process of thermally-activated process, the relaxation time (τ), calculated via relationship ($2\pi f_{\max} \tau = 1$), is obtained from Arrhenius expression:

$$\tau^M = \tau_0 \exp\left(-\frac{E_a^M}{k_B T}\right) \quad (12)$$

Where (τ_0 and k_B) are ,respectively, pre-exponential factor and Boltzmann's constant.

E_a^M was obtained via setting $\ln(\tau)$ vs $1000/T$ (**Fig. 4(c)**). As expected, the reported E_a^M value of the $\text{LSNM}_{0.70}\text{T}_{0.30}$ ceramic was approximately the same as that obtained by measuring $\sigma(\omega)$ and in the region of those obtained for some other samples. This implies that conduction mechanism and the relaxation behavior are connected to same source.

Figure 4 (d) demonstrates the scaled coordinates $M''(\omega)$ for the spectra mentioned above, displayed on the modulus line via obtained the graph $M''(\omega)/M''_{\max}(\omega)$ of the $\text{LSNM}_{0.70}\text{T}_{0.30}$ sample vs the normalized frequency ω/ω_{\max} . If all scaling curve values collapse into one main graph, them distribution of relaxation times is not influenced by the T [40].

As expected, a dispersive behavior emerged of the $\text{LSNM}_{0.70}\text{T}_{0.30}$, showing that relaxation behavior for the $\text{LSNM}_{0.70}\text{T}_{0.30}$ is of non-Debye process and described by presence of a poly-dispersive relaxation process in $\text{LSNM}_{0.70}\text{T}_{0.30}$, which is in consistent with results of the IS.

3.2.4 Dielectric results

To evaluate the dielectric behaviors, complex permittivity $\epsilon^*(\omega)$ was utilized. This latter was can be extracted from the Z^* as [41]:

$$\epsilon^*(\omega) = \frac{1}{jC_0\omega Z^*} = \frac{Z''}{\omega C_0(Z'^2 + Z''^2)} + j \frac{Z'}{\omega C_0(Z'^2 + Z''^2)} = \epsilon'(\omega) + j\epsilon''(\omega) \quad (13)$$

Where $\epsilon'(\omega)$, $\epsilon''(\omega)$ are the real part and the imaginary part of $\epsilon^*(\omega)$, respectively.

Figure 5 (a) displays the frequency related to the $\epsilon'(\omega)$ at selected temperatures of $\text{LSNM}_{0.70}\text{T}_{0.30}$ sample.

At low frequencies, the $\epsilon'(\omega)$ that tends not to be influenced by frequency exhibits colossal values that may be ascribed to the effect of the interfacial polarization achieved using Koop's theory [42], known as Maxwell-Wagner-Sillars phenomenon. Indeed, Maxwell-Wagner mechanism may be described by investigating the heterogeneity of the structure with respect to semiconductor grains divided by insulating grain boundaries with diverse electrical conductivities. Thanks to the electron jump between $\text{Mn}^{3+}/\text{Mn}^{4+}$, the charge carriers stuck up at the grain boundaries and created a polarization. As frequencies were increased, charge carriers reversed their orientation more frequently at grain boundary and, as a result, reduced the polarization [43]. The deformation produced by rise of temperature, at fixed frequency, can account for the reduction of the $\epsilon'(\omega)$ in $\text{LSNM}_{0.70}\text{T}_{0.30}$ compound. The same process has been demonstrated in some sample semiconductors [44,45].

Figure 5 (b) displays the change of the frequency of $\varepsilon''(\omega)$ at several temperatures of the sample LSNM_{0.70}T_{0.30}. As can be observed, at low frequencies, the data showed high values of $\varepsilon''(\omega)$ confirming presence of all polarization phenomena in the LSNM_{0.70}T_{0.30} sample.

However, as frequency increased, $\varepsilon''(\omega)$ decreased as the electric dipoles located in the LSNM_{0.70}T_{0.30} cannot follow the electric field applied to the ac [46].

It should be noted that the absence of peaks in the data of $\varepsilon''(\omega)$ suggests that the polarization mechanism in the LSNM_{0.70}T_{0.30} is driven via a jumping behavior as described previously [46]. In fact, $\varepsilon''(\omega)$ can be represented via the Giuntini expression provided via [47]:

$$\varepsilon''(\omega) = a(T)\omega^m \quad (14)$$

Where

$$m = -4kT/W_c \quad (15)$$

In these equations, a (T) is a constant related only to temperature, m is a parameter explaining the interaction between electric dipoles, and W_c is the maximum potential barrier height. We plotted the evolution of the Ln (ε'') v.s Ln (ω) at several temperatures (in the inset of **Fig.5 (c)**). The resulting linear graphs with slopes in the range of -1 suggest that dielectric losses are controlled by the σ_{dc} process [48].

These plots were applied to calculate the values of W_c depicted in **Fig.5 (d)**. As observed, W_c rose due to the deformation produced via temperature increase.

The similar process was found in Pr_{0.8-x}Bi_xSr_{0.2}MnO₃ [49], in La_{0.67-x}Eu_xBa_{0.33}Mn_{0.85}Fe_{0.15}O₃ [50] and in Pr_{0.5-x}Gd_xSr_{0.5}MnO₃ [51].

In order to verify the dominance of σ_{dc} on the dielectric properties of the LSNM_{0.70}T_{0.30} manganite resulting in the elimination of the relaxation behavior in $\varepsilon''(\omega)$ curve, we estimated the dielectric loss by the formula below, that is usually used at low frequencies [52]:

$$\sigma_{AC}(\omega) = \varepsilon_0 \omega \varepsilon'' \quad (16)$$

So, at low frequency, the $\varepsilon''(\omega)$ is almost entirely assigned to σ_{dc} . Therefore, relaxation mechanism in dielectric curves is totally obscured by σ_{dc} .

4. Conclusion

The LSNM_{0.70}T_{0.30} manganite was prepared via solid-state process. The electrical characteristics are studied by impedance spectroscopy over a wide interval of frequency and various temperatures. The complex impedance investigation reveals the presence of an electrical relaxation mechanism in the LSNM_{0.70}T_{0.30} sample. The σ_{ac} conductivity established that based on Jonscher law, σ_{ac} is described at low temperatures by Non-overlapping Small

Polaron Tunneling model and at high temperatures Correlated Barrier Hopping model. From dc conductance measurement, the electronic conduction appears to be thermally activated, suggesting the existence of semiconductor behavior. Additionally, the dielectric constant curves were applied to study the relaxation dynamics of charge carriers. In fact, Debye-like relaxation was interpreted using the polarization of spatial charges following Maxwell-Wagner model and Koop's phenomenological theory.

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Figures

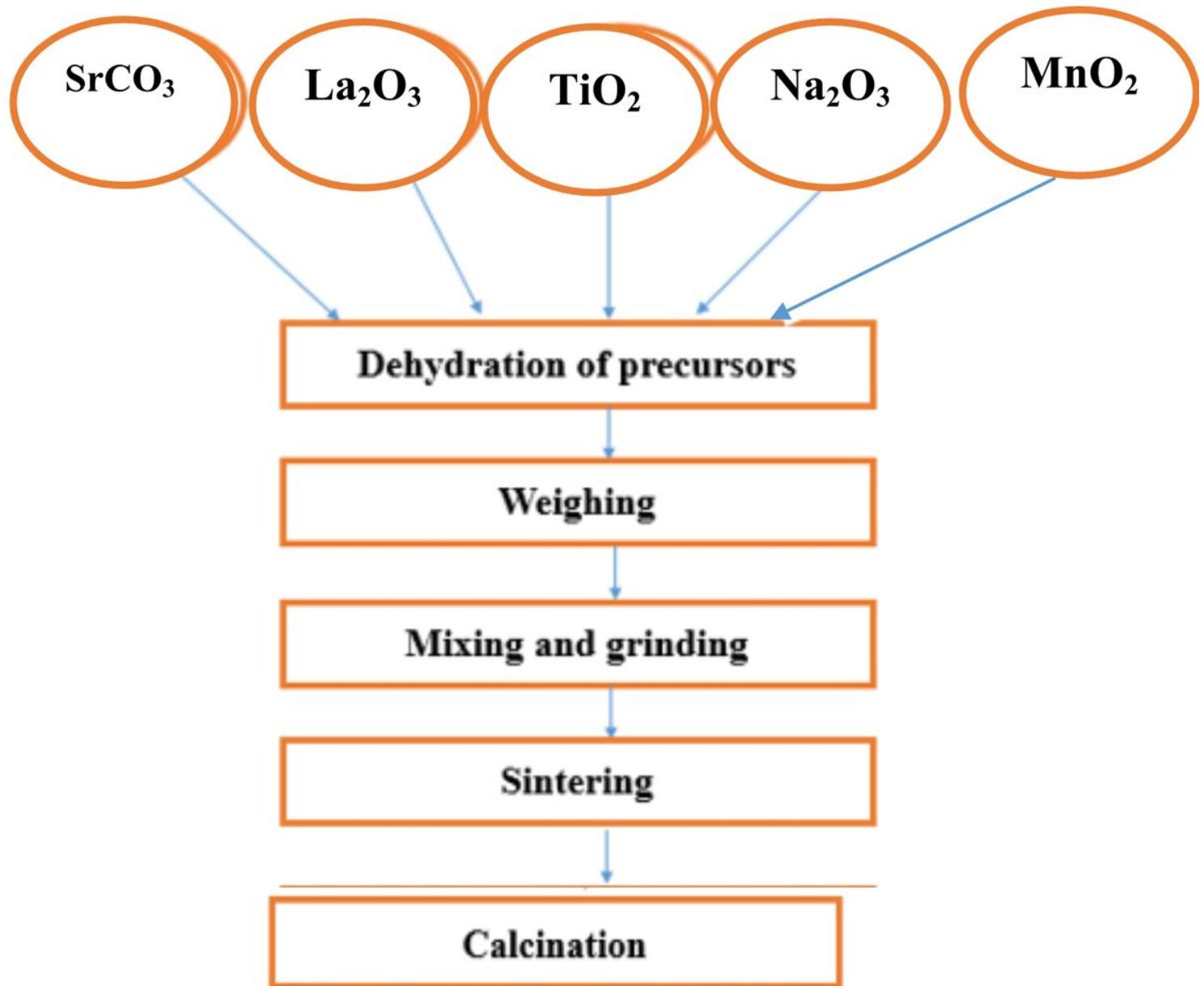


Figure 1

Flowchart diagram for the preparation of LSNM0.70T0.30 sample.

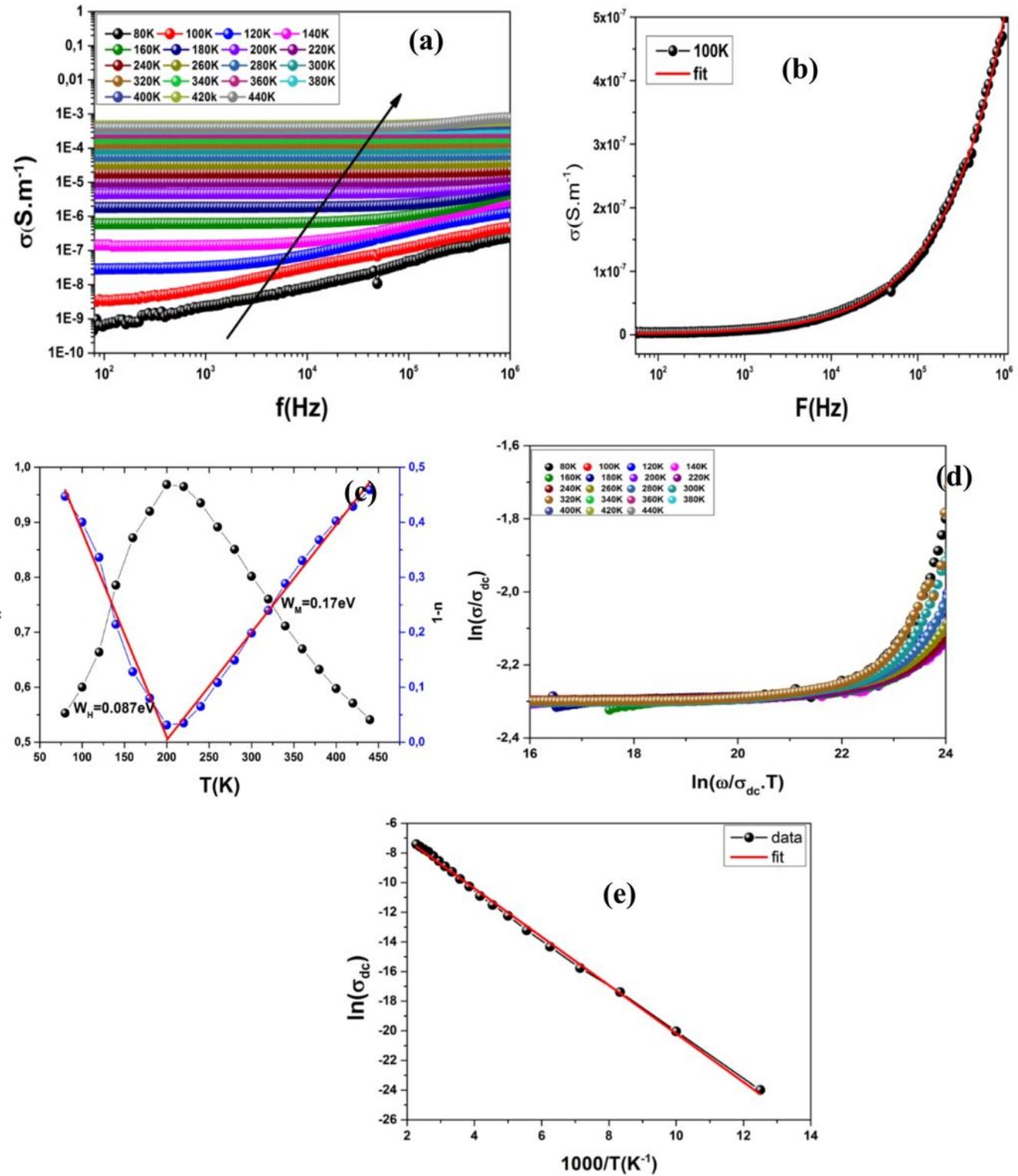


Figure 2

Electrical conductivity behavior of the LSNNM0.70T0.30 sample. (a) Frequency dependence of the electrical conductivity at several temperatures. Inset: Variation of the dc component versus the temperature. (b) Comparison of the experimental data and theoretical fit curve for the temperature 280 K. Inset: the variation of the exponents s and $(1-s)$ with temperature. (c) Variation of Log ($\sigma_{dc}T$) vs $1000/T$. (d) Reduced conductivity.

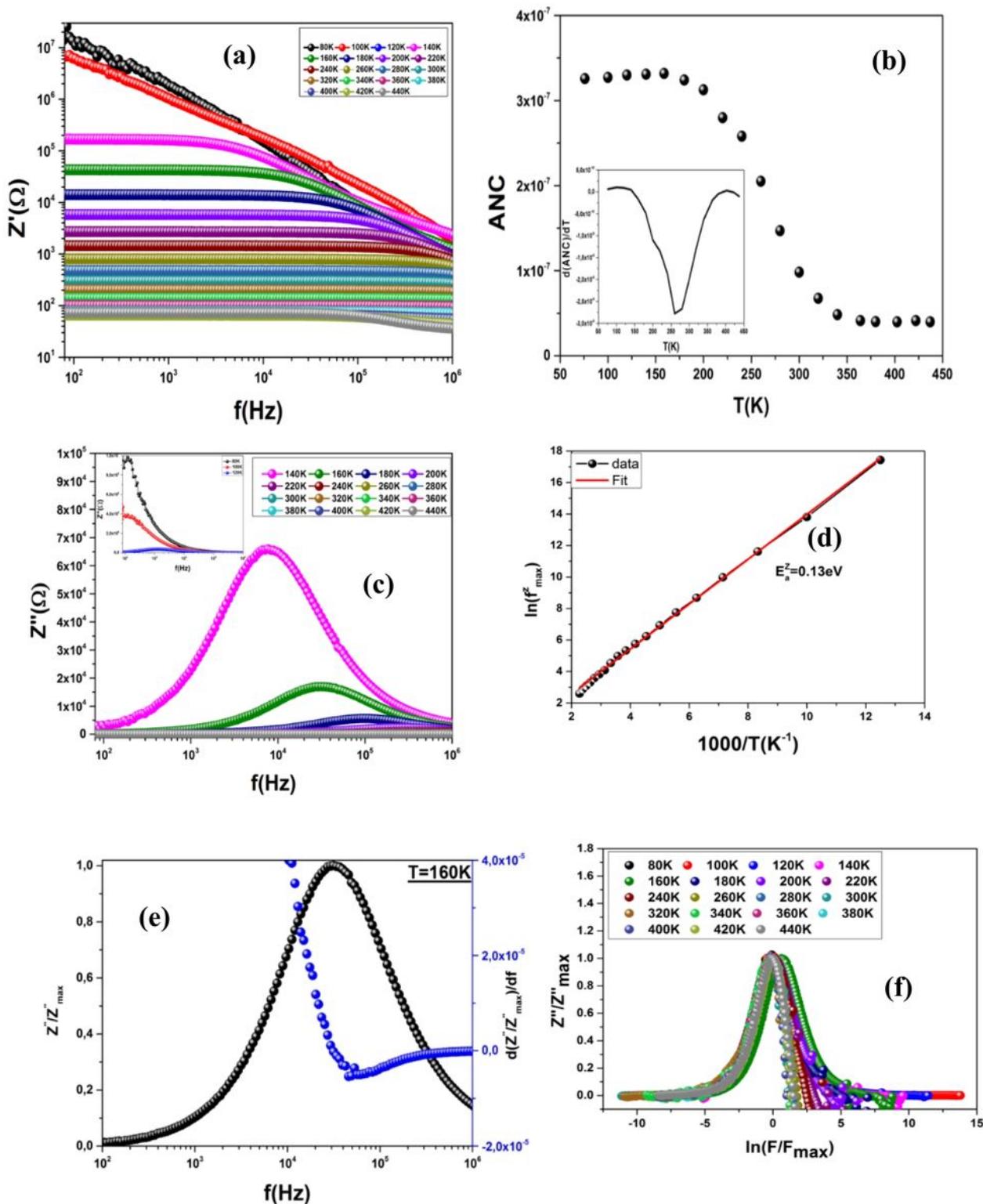


Figure 3

(a) Spectra of the real part of impedance (Z'), (b) the ANC of LSNM0.70T0.30 ceramic, (c) Spectra of the impedance (Z''), (d) Computation of the activation energy, (e) Variation of Z''/Z''_{max} versus f/f_{max} for LSNM0.70T0.30, (f) Spectra of $d(Z''/Z''_{\text{max}})/df$ and Z''/Z''_{max} at 260K.

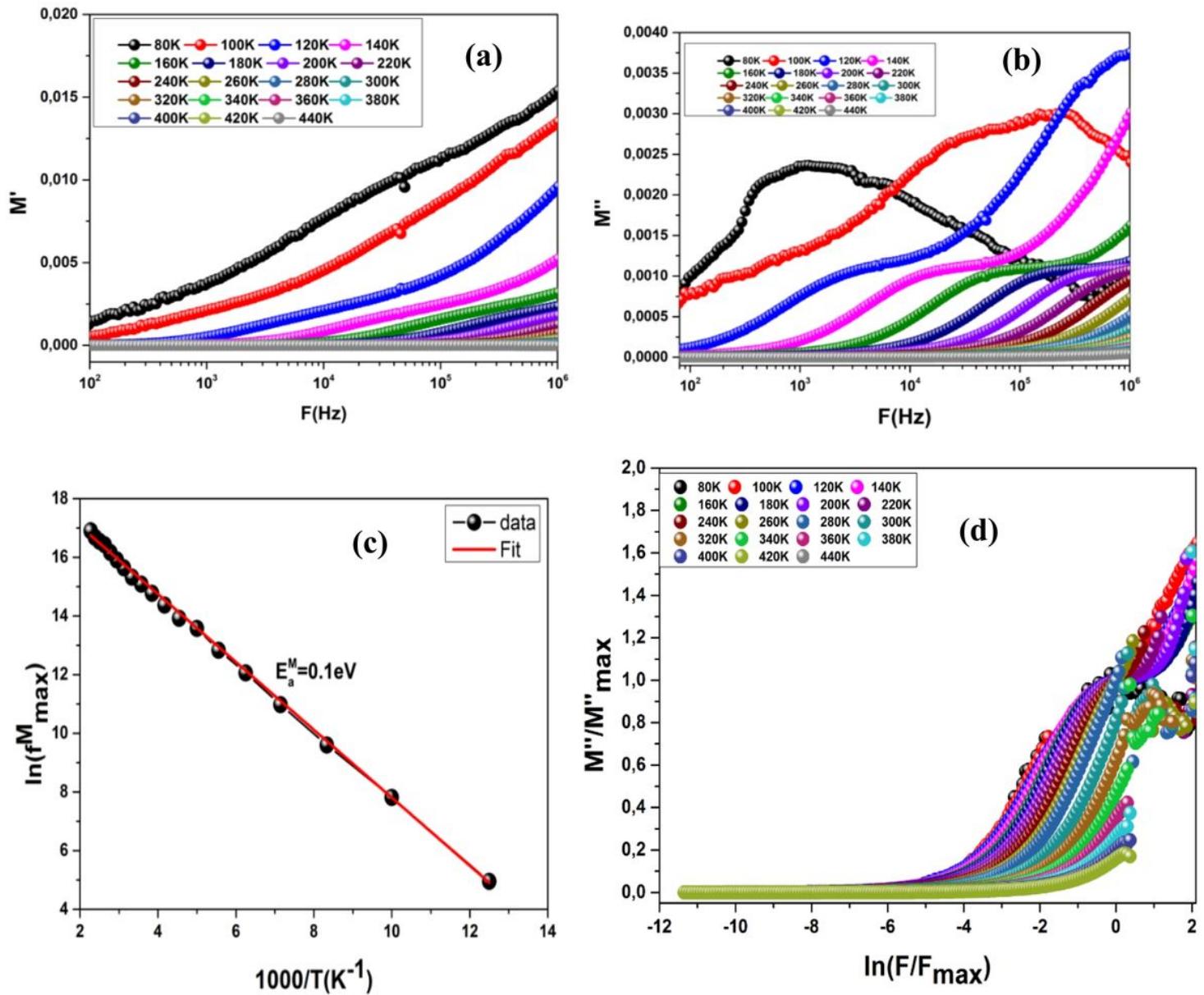


Figure 4

(a) Spectra of the real part (M') of the complex modulus, (b) Spectra of the imaginary part (M'') of complex modulus, (c) Relaxation time versus the inverse of T , (d) Reduced electrical modulus vs the reduced frequency of LSNM0.70T0.30 ceramic.

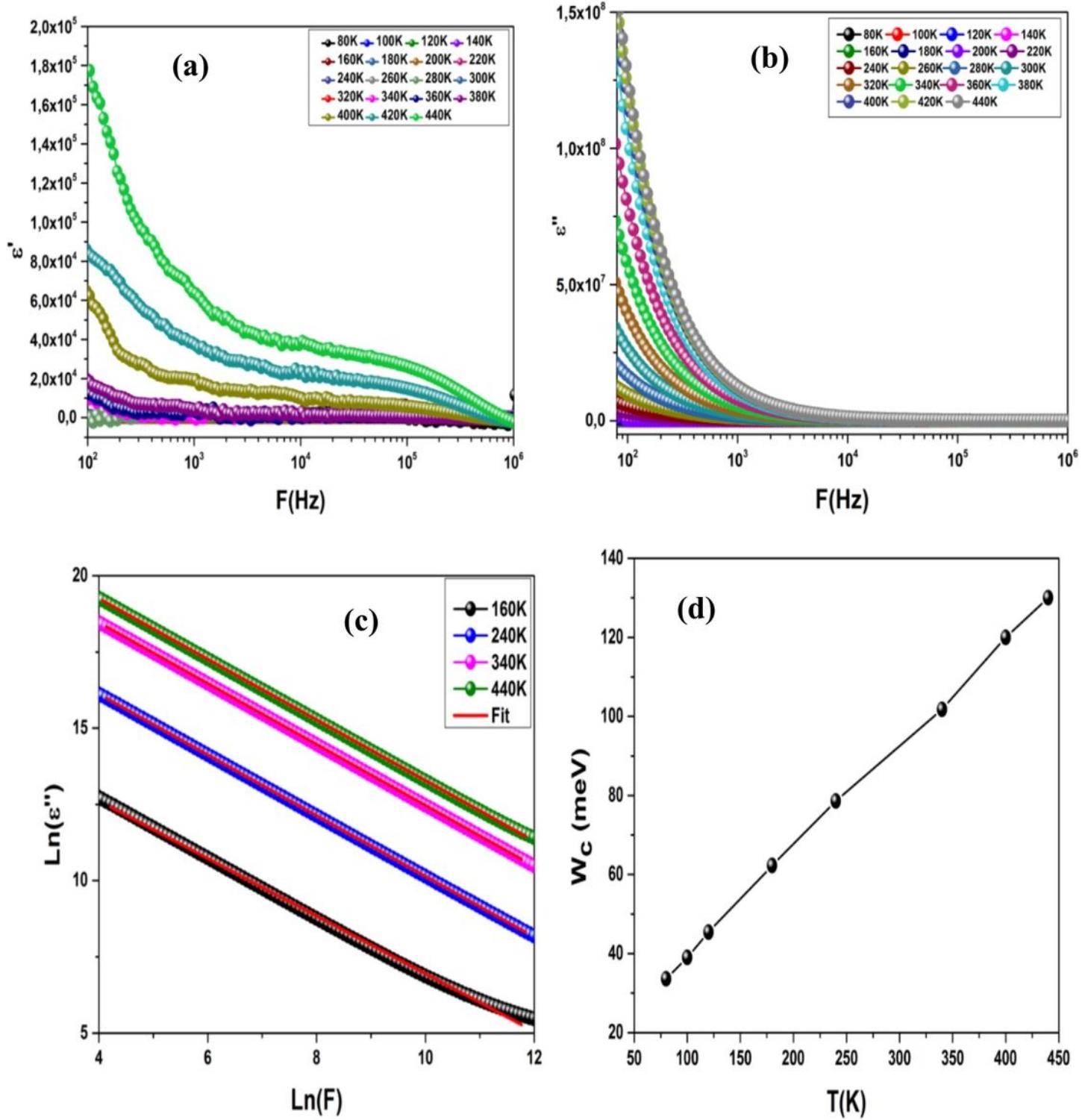


Figure 5

(a) Spectra of the permittivity ϵ' , (b) Spectra of the permittivity ϵ'' , (c) Evolution of $\ln(\epsilon'')$ versus $\ln(\omega)$ for LSNM0.70T0.30, (d) Evolution of the energy W_c at different temperatures for LSNM0.70T0.30 ceramic.